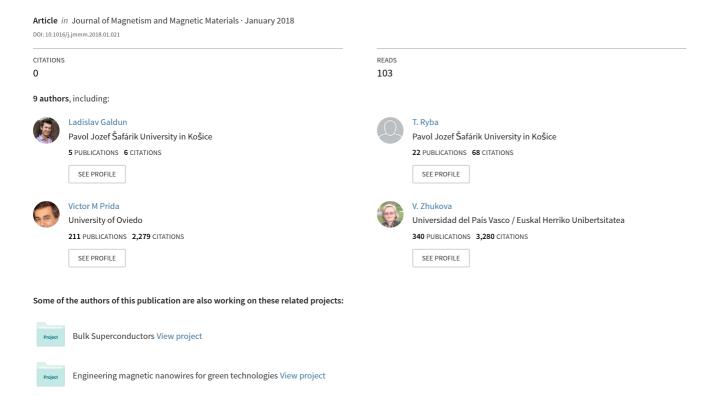
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PII: S0304-8853(17)33744-7

DOI: https://doi.org/10.1016/j.jmmm.2018.01.021

Reference: MAGMA 63599

To appear in: Journal of Magnetism and Magnetic Materials

Received Date: 1 December 2017 Revised Date: 8 January 2018 Accepted Date: 10 January 2018



Please cite this article as: L. Galdun, T. Ryba, V.M. Prida, V. Zhukova, A. Zhukov, P. Diko, V. Kavečanský, Z. Vargova, R. Varga, Monocrystalline Heusler Co₂FeSi alloy glass-coated microwires: fabrication and magneto-structural characterization, *Journal of Magnetism and Magnetic Materials* (2018), doi: https://doi.org/10.1016/j.jmmm.2018.01.021

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Monocrystalline Heusler Co₂FeSi alloy glass-coated microwires: fabrication and magneto-structural characterization

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Abstract

Large scale production of single crystalline phase of Heusler Co₂FeSi alloy microwire is reported. The long microwire (~ 1 km) with the metallic nucleus diameter of about 2 μ m is characterized by well oriented monocrystalline structure (B2 phase, with the lattice parameter a=5.615 Å). Moreover, the crystallographic direction [101] is parallel to the wire's axis along the entire length. Additionally, the wire is characterized by exhibiting a high Curie temperature (Tc>800 K) and well-defined magnetic anisotropy mainly governed by shape. Electrical resistivity measurement reveals the exponential suppression of the electron-magnon scattering which provides strong evidence on the half-metallic behaviour of this material in the low temperature range.

Keywords: Heusler alloy, single crystal, microwire.

1. Introduction

The production of spintronic devices has intensified the search for new materials, especially halfmetals, exhibiting room temperature ferromagnetism [1, 2]. This extraordinary behaviour can be understood via distinct character of energy bands for spin up and spin down states. While spin up band overlaps the Fermi energy level (E_f) and demonstrates a metallic character, the spin down band shows a semiconductor-like gap at the E_f [3, 4]. Heusler alloys, which are well-known for their diverse and multifunctional magnetic behaviour in various fields of application, have recently attracted much attention as they are theoretically predicted to exhibit 100% spin polarization at E_f [5 - 7].

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Full-Heusler alloys with the compositional stoichiometry (X_2YZ) crystallize in $L2_1$ structure. Here X and Y are transition or rare earth metals (lanthanides) and Z represents a main group element [8, 9]. Among half-metallic alloys, Co-based full-Heusler compounds are most promising materials due to their high Curie temperatures ($Tc \sim 1100 \text{ K}$), high magnetic moment ($\sim 6 \mu_B/f.u.$) and low Gilbert damping constant ($\gamma = 0.004$) [10].

Although the $L2_I$ structure is a highly ordered structure, the formation of disordered phases (B2, A2, etc.) may occur during the fabrication of alloys. The exchange between atomic positions of elements for the X_2YZ Heusler alloy in $L2_I$ lattice can result in different structural disorders: a) exchange between Y and Y atoms results in Y atoms results in Y and Y atoms results in Y atoms results in Y atoms results in Y atoms results in the Y disorder and Y atoms results in the Y disorder. It was predicted by theoretical calculations [11, 12], that the Y-Y disorder (Y disord

Due to the above mentioned disorder, the production of Heusler alloys brings some disadvantages [13]. Heusler alloys are usually prepared by arc-melting method. Moreover, they require further suitable thermal treatment for a long time (from several hours up to entirely weeks) for obtaining the correct high ordered phase [14]. It was shown earlier [15], that rapid quenching by Taylor-Ulitovsky technique offers the production of glass-coated metallic microwires without the necessity of long thermal treatments. This single-step method with a high quenching rate of up to 10⁷ K/s allows to prepare in a short time (of the order of few minutes) up to kilometres of the wire [16]. It is worth mentioning, that due to its high quenching rate it is possible to produce Heusler-based microwires with single crystalline phase and well-defined magnetic anisotropy [17-19].

In the given contribution, we present the basic structural and magnetic characterization of glass-covered Heusler Co₂FeSi alloy microwires prepared by Taylor-Utilovski technique. We show that it is

possible to produce up to kilometres of monocrystalline Heusler-based microwires in few minutes using this simple production technique that may enhance the suitability of Co₂FeSi for spintronic applications.

2. Material and methods

The starting master alloy with nominal composition of Co₅₀Fe₂₅Si₂₅ was prepared using arc-melting of pure elements (99.99%) under argon atmosphere. Magnetic glass-coated microwires were fabricated by the Taylor-Ulitovsky technique, which consists on drawing and casting directly from the melted master alloy [20]. The diameter of inner metallic nucleus of microwire sample is around of 2 μm, while the diameter of external Pyrex coating is around 20 μm.

Chemical composition, size and shape of the microwire were characterized by scanning electron microscopy (SEM, JEOL-6100) with energy-dispersive X-ray spectroscopy (EDX) option. The microstructural and crystallographic characteristics were investigated by electron backscatter diffraction analysis (EBSD) using SEM TESCAN MIRA 3. The structure and crystalline phase were characterized by single-crystal X-ray diffraction analysis using Oxford Diffraction Xcalibur Nova diffractometer with $CuK\alpha$ radiation ($\lambda = 1.5418$ Å). Magnetic hysteresis loops and temperature dependence of magnetization were measured on a single piece of the microwire with the length of 10 mm using a SQUID MPMS Quantum Design, along both, the parallel and perpendicular direction with respect to the axis of the wire, in the temperature range from 10 - 400 K and in the external fields up to 10kOe. The resistivity was measured using standard four probe method in the temperature range from 8 K to 300 K by employing a Physical property measuring system (PPMS) Quantum Design platform. In order, to make the contacts the glass coating was released mechanically from the ends of the microwire. Afterwards, the contacts were made on metallic nucleus.

3. Results and discussion

Cross-section SEM image of glass-coated microwire shown in Figure 1(a) displays small metallic core with smooth surface and diameter around of 2.0 µm that is covered by glass-coating with total

diameter of 20.4 µm. Chemical composition of the metallic nucleus Co_{49.0}Fe_{25.6}Si_{25.4} checked by SEM EDX is in a good agreement with the expected one.

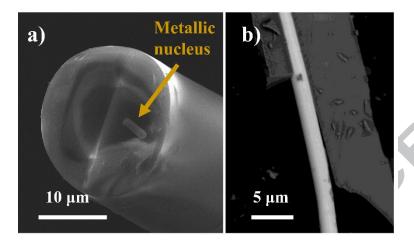


FIG.1. (a) SEM micrograph showing the cross section of a Co₂FeSi glass-coated microwire. The metallic core is marked with yellow arrow and (b) SEM micrograph showing the metallic core after being released from the glass coating without any grain boundaries.

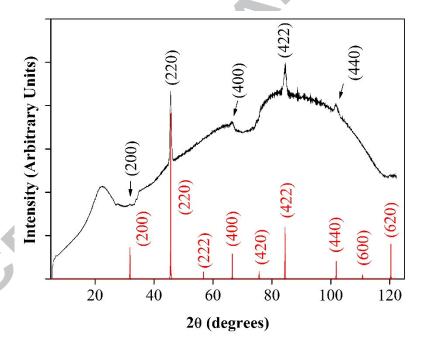


FIG.2. X-ray diffraction profile of glass-coated Co₂FeSi microwire. Experimental (black) and theoretical data (red) obtained by fitting.

Figure 2 displays the X-ray diffraction analysis of the glass-coated Co₂FeSi microwires showing a wide plateau that corresponds to the glass-coating together with the crystalline patterns of the metallic

nucleus corresponding to the B2 phase with a lattice parameter a = 5.615 Å, which is similar to the values presented in other works (5.66 Å) [13].

It has been shown earlier [21] that the production of glass coated microwires leads to the formation of oligocrystalline structure, where large crystals (few tens of μm) appear along the wire. However, when the production is provided carefully with well selected diameter of the metallic nucleus and glass coating, the monocrystalline structure of the inner metallic alloy can appear. Figure 3 shows the EBSD analysis performed on an area of the surface of Co₂FeSi microwire after mechanical removal of the external glass coating. Firstly, no grain boundary has been found along the entire wire. Additionally, various analysis of randomly selected pieces of the microwire revealed the same results, which points to the monocrystalline structure of entire microwire with the crystalline [101] direction lying parallel to the wire saxis. Such preferred orientation can be understood in terms of the tensile stresses induced by drawing and quenching of metallic nucleus during microwire production. During crystallization, the metallic nucleus undergoes strong axial stresses induced by the surrounding glass on the inner metallic alloy due to different thermal expansion coefficient between Pyrex and metallic nucleus.

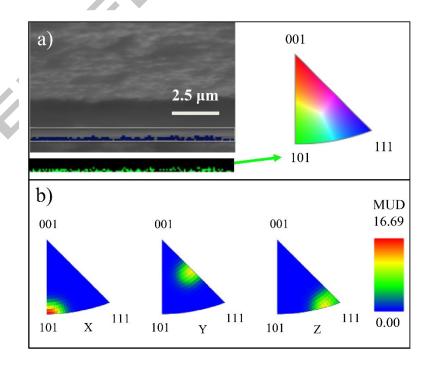


FIG.3. (a) EBSD analysis of Co2FeSi microwire and inverse pole figures (b) show monocrystalline structure with the crystallographic orientation [101] lying parallel to the microwire's axis.

Volume hysteresis loops (FIG.4) measured along both, the parallel and perpendicular direction of the applied magnetic field with respect to the wire's axis, revealed well-defined magnetic anisotropy of the metallic nucleus. The comparison between both hysteresis loops points out that the easy magnetization axis is parallel aligned to the microwire's axis. The hysteresis loop for parallel direction shows higher coercivity (118.8 Oe) comparing to the perpendicular one (5.6 Oe). This points to the fact that the domain wall propagation dominates in the parallel direction to the easy magnetization axis, while the hysteresis loop measured in the perpendicular direction reveals dominant magnetization rotation process (hard magnetization axis).

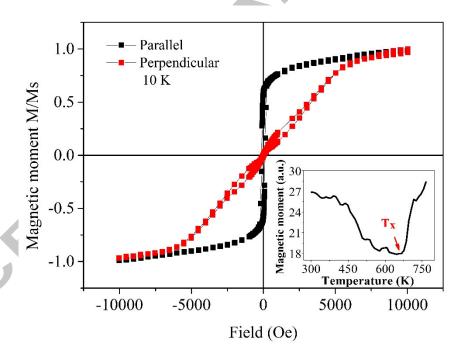


FIG. 4. Volume magnetic hysteresis loops measured at 10 K along the parallel (black) and perpendicular (red) directions of the applied field with respect to the wire's axis and temperature dependence of magnetization (insert) for Co₂FeSi glass-coated microwire.

Temperature dependence of saturation magnetization of Co₂FeSi glass-coated microwire (insert in FIG. 4) shows typical ferromagnetic behaviour with decreasing magnetization up to 640K. Above this

temperature, magnetization starts to increase most probably due to the secondary crystallization that deteriorates the magnetic properties [15]. The irregular shape of the curve may be caused due to the annealing of the wire, which relieves the internal stresses in the metallic nucleus from the glass coating (under 640 K) [22]. Moreover, the releasing of complex stresses distribution with distinct directions takes effect in the increase of the magnetization due to its rotation towards the easy magnetization axis. The Curie temperature, T_C , of Co₂FeSi Heusler alloys is much higher than crystallization temperature ($T_x = 670$ K) and higher than our measuring interval ($T_C \sim 1100$ K [10]).

As previously mentioned in the introduction, the B2 phase is a Y-Z disordered structure, which may reduce the values of spin polarization. However, recent theoretical investigation on the spin polarization of fully ordered $L2_1$ and fully disordered B2 structure of Co_2FeSi Heusler alloy reveals that both systems are half metallic. [2]

Lately studies [13, 23-26] have shown that the half-metallic character and structural disorder of Heusler alloys can be predicted by simple electrical resistivity variation with temperature. In our case, the resistivity data was found to fit well with the relations presented in the published work by *Bombor et al*, [26]. By taking into account the predicted half-metallic character of the B2 disordered phase of Co₂FeSi Heusler alloy, the absence of minority spin states at Fermi level, E_F , implies the existence of an energy gap Δ for only one spin direction.

In ordinary ferromagnets the resistivity, ρ , shows a characteristic ${}^{\sim}T^2$ dependence that arises from electron-magnon (i.e., spin-flip) scattering. In the case of half-metallic ferromagnets, the spin flips of conduction electrons should be suppressed due to the energy gap Δ . Therefore, the characteristic ${}^{\sim}T^2$ dependence is expected to be exponentially suppressed within the temperature range where $k_BT \leq \Delta$. Additionally, the resistivity of a metal is usually dominated by electron-phonon scattering characterized by a linear temperature dependence at elevated temperatures ($T \geq 50$ K).

The attempt to fit resistivity variation with temperature, ρ (T) (FIG. 5), of the monocrystalline Co₂FeSi metallic nucleus with quadratic and quadratic plus linear temperature dependence fails completely. Therefore, we fitted resistivity with combined scattering of residual (ρ_R), magnonic (ρ_M), and phononic (ρ_P) contributions according to previous study [26]:

$$\rho = \rho_R + \rho_M(T) + \rho_P(T). \tag{1}$$

The residual resistivity (ρ_R) is temperature independent and is caused by the defects of the crystal lattice or additional strong stresses induced by the glass-cover on metallic nucleus. The usually quadratic magnonic term $\rho_M(T)$ is expected to be exponentially suppressed because of the gapped spin-flip scattering [26]. The resistivity data in the low temperature interval ($T \le 88$ K) was found to fit well with the electron-magnon scattering dependence empirically weighted by a Boltzmann factor [26],

$$\rho_M(T) = CT^2 \exp\left(\frac{-\Delta}{k_B T}\right). \tag{2}$$

The parameter C presents the measure of the strength of the magnon scattering process. The phononic part of the scattering process (ρ_P) is well described by the Bloch-Grüneisen formula,

$$\rho_{P}(T) = A \left(\frac{T}{\Theta_{D}}\right)^{5} \int_{0}^{\Theta_{D}/T} \frac{x^{5}}{(e^{x} - 1)(1 - e^{-x})} dx.$$
 (3)

The resistivity fit yields the Debye temperature $\Theta_D = 330$ K and an energy gap

$$\Delta / k_B = 37 K, (\Delta = 3.2 meV). \tag{4}$$

The estimated value of the Debye temperature is in a good agreement with the one obtained in a previous study [26]. On the other hand, the extracted gap size is smaller as compared to the theoretical calculations by more than one order and is also in a good agreement with previous experimental results [26]. In spite of that, the observed experimental suppression of spin-flip scattering confirms the half-metallic character. However, the extracted value of Δ points to the fact, that the 100 % spin polarization of the conduction electron on the Fermi level is present only for the temperature interval $k_BT < \Delta$.

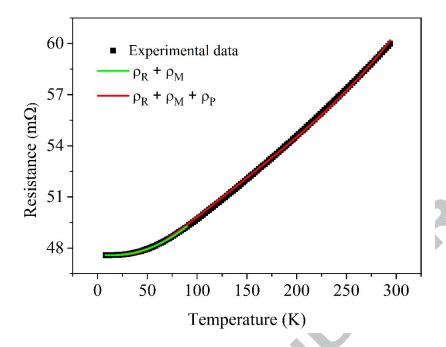


FIG. 5. Temperature dependent electrical resistivity for Co_2FeSi glass-coated microwire. The experimental values are displayed as black line. While the green line represents the fit of $\sim T^2$ magnonic dependence with the additional Boltzmann factor, the red line shows the fit with magnonic-phononic temperature dependence.

4. Conclusion

In conclusion, we report on fabrication and characterization of monocrystalline Heusler Co₂FeSi glass-coated microwire prepared by Taylor-Ulitovsky technique. The wire is characterized by monocrystalline B2 structure (a = 5.615 Å) along the entire length, which is characterized by the mutual disorder between Y (Fe) and Z (Si) atoms. Additionally, above mentioned monocrystalline structure is well oriented having [101] crystallographic direction parallel to the wire's axis. Apart from high Curie temperature, such a wire shows well-defined magnetic anisotropy with the easy magnetization axis parallel to the wire's axis. The electrical transport measurement points to the half-metallic features of this ferromagnetic material. However, half-metallic behaviour was only observed in the temperature range of $T \le 88$ K. Taking into account that Taylor-Ulitovsky method allows production of wire with the diameter down to 90 nm [27], it is clear that easy and low-cost preparation of large amount of

monocrystalline Heusler-type microwires offers new possibilities in spintronic applications, where materials with high spin polarization is desired.

Acknowledgements

The authors thank to Prof. A. Feher for the fruitful discussion. This work was supported by NanoCEXmat ITMS 26220120035, Slovak Grant Agency [grant number VEGA 1/0060/13], Slovak Grant Agency [grant number APVV-16-0079], and Slovak Grant Agency [grant number APVV-0027-11]. Spanish MINECO research projects [grant number MAT2013-48054-C2-2-R] and [grant number MAT2016-76824-C3-3-R], together with FICyT and Consejería de Economía y Empleo from Principality of Asturias under project [grant number GIC-FC-15-GRUPIN14-085] are gratefully acknowledged. The technical assistance provided by the Scientific-Technical Services (SCTs) of the University of Oviedo is also recognized.

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